<u>OMRON</u>

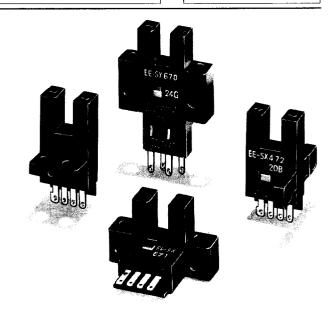
RS 219-2274 SX670 RS 219-2280 SX671 RS 219-2296 SX672 RS 219-2303 SX673

EE-SX670/470

Photomicrosensor

Photomicrosensor with 100-mA Switching Capacity that can be Built into Equipment

- Standard, L-shaped, T-shaped, and close mounting models available.
- Select from eight output variations, including LIGHT-ON or LIGHT-OFF/ON models.
- Response frequency as high as 1 kHz.
- Easy operation monitoring with bright LIGHT-ON indicator.
- Wide operating voltage range (5 to 24 VDC) makes smooth connection of the photomicrosensor with TTLs, relays, and programmable controllers (PC) possible.
- Dust-proof slit.



Ordering Information

Appearance	Sensing method	Sensing distance	Output configuration	Model	Weight
Standard Transm	Transmissive type	5 mm	Light-OFF/ON*	EE-SX670	Approx. 3.1 g
COLLEGE			Light-ON	EE-SX470	
L-shaped	7		Light-OFF/ON*	EE-SX671	Approx. 3.0 g
			Light-ON	EE-SX471	
T-shaped			Light-OFF/ON*	EE-SX672	Approx. 2.4 g
Close			Light-ON	EE-SX472	
Close-mounting			Light-OFF/ON*	EE-SX673	Approx. 2.3 g
644			Light-ON	EE-SX473	

^{*}The Light-OFF/ON models can be used as Light-OFF models when the L terminal and positive (+) terminal are short-circuited. To use them as Light-ON models do not short-circuit these terminals.

Specifications -

■ Ratings

ltem		Standard		L-shaped		T-shaped		Close-mounting	
		EE-SX670	EE-SX470	EE-SX671	EE-SX471	EE-SX672	EE-SX472	EE-SX673	EE-SX473
Supply voltage		5 to 24 VD	C ±10%, rip	ole (p-p): 10	% max.		•	•	·
Current consumption		35 mA max	ζ.						
Standard refer	ence object	Opaque: 0	.8 x 2 mm	****					
Differential distance		0.025 mm							
Control output		At 5 to 24 ' When drivi		0-mA load c -mA load cu	urrent (I _C) w rrent (I _C) wit	rith a residua h a residual	al voltage of voltage of 0	0.8 V max. .4 V max.	
Output configuration	Transistor on output stage without detecting object	OFF (ON) (see note 1)	ON	OFF (ON) (see note 1)	ON	OFF (ON) (see note 1)	ON	OFF (ON) (see note 1)	ON
	Transistor on output stage with detecting object	ON (OFF) (see note 1)	OFF	ON (OFF) (see note 1)	OFF	ON (OFF) (see note 1)	OFF	ON (OFF) (see note 1)	OFF
Indicator (see note 2) Without detecting object With detecting object		ON							
		OFF							
Response frequency		1 kHz max. (3 kHz typ.)							
Connecting method		EE-1001/1006 Connectors; soldering terminals							
Light source		GaAs infrared LED with a peak wavelength of 940 nm							
Receiver		Si phototra	Si phototransistor with a sensing wavelength of 850 nm max.						

Note: 1. The word ON or OFF in the parenthesis expresses the operating status of the LIGHT-ON model when the L terminal and positive (+) terminal are short-circuited.

2. The indicator is GaP red LED (peak emission wavelength: 690 nm).

■ Characteristics

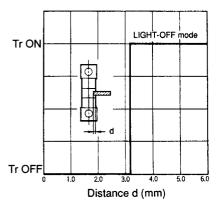
Ambient illumination (see note 1)	Fluorescent light: 1,000 ℓ x max.		
Ambient temperature	Operating: -10° to 55°C Storage: -25° to 80°C		
Ambient humidity	Operating: 45% to 85% Storage: 35% to 95%		
Vibration resistance	Destruction: 20 to 2,000 Hz, (with a peak acceleration of 10G's), 1.5-mm double amplitude for 2 hrs (with 4-minute cycles) each in X, Y, and Z directions		
Shock resistance Destruction: 500 m/s² for 3 times each in X, Y, and Z directions			
Soldering heat resistance	260°±5°C(see note 2) when the portion between the tip of the terminals and the position 1.5 mm from the terminal base is dipped into the solder for 10±1 seconds		

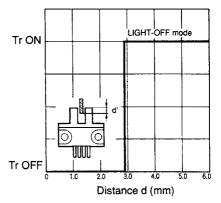
Note: 1. The ambient illuminance is measured on the surface of the receiver.

2. This conforms to MIL-STD-750-2031-1.

Engineering Data

Sensing Position Characteristics (Typical)



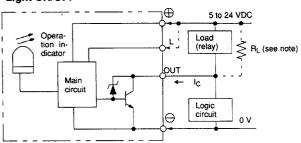


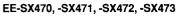
Operation

■ Output Circuit Diagrams

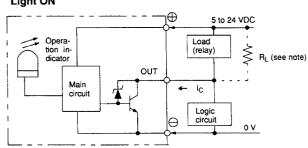
EE-SX670, -SX671, -SX672, -SX673







Light ON



Note: Connect R₁ only when a logic circuit is driven.

■ Timing Chart

Light ON

EE-SX670, -SX671, -SX672, -SX673

(When terminals L and \oplus are short-circuited)		(When terminals L and \oplus are open		
	Incident Interrupted			Incident Interrupted
LIGHT indicator (red)	ON OFF		LIGHT indicator (red)	ON OFF
Output transistor	ON OFF		Output transistor	ON
Load (relay)	Operates Releases		Load (relay)	Operates ————————————————————————————————————
Output voltage			Output voltage	LJ

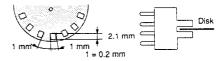
EE-SX470, -SX471, -SX472, -SX473 Light ON

	Incident Interrupted	12 14 14 14 14 14 14 14 14 14 14 14 14 14
LIGHT indicator (red)	ON OFF	
Output	ON	
transistor Load (relay)	OFF Operates	
• • • • • • • • • • • • • • • • • • • •	Releases	
Output voltage (logic)	H L	

■ Rotating Disk for Measuring Response Frequency EE-SX670/SX470

(logic)

Light OFF

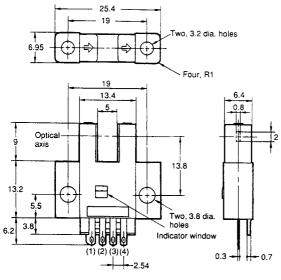


Dimensions

Note: All units are in millimeters unless otherwise indicated.

EE-SX670 EE-SX470



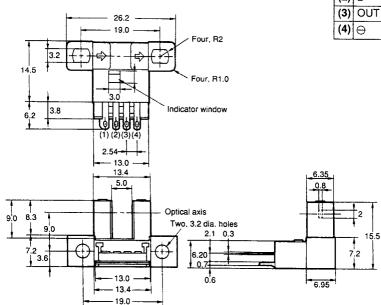


Terminal Arrangement

(1)	⊕	Vcc
(2)	L	L
(3)	OUT	OUT PUT
(4)	θ	GND (0 V)

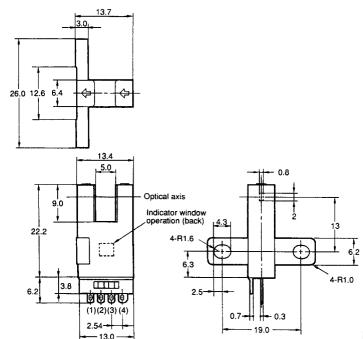
EE-SX671 EE-SX471





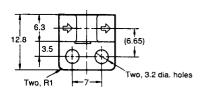
EE-SX672 EE-SX472

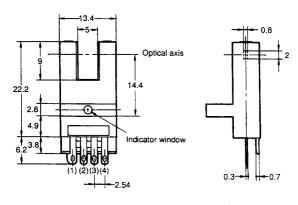




EE-SX673 EE-SX473

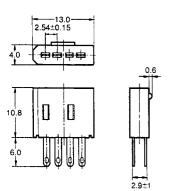






EE-1001 Connector





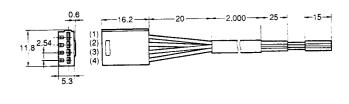
EE-SX67 + EE-1001

Terminal Arrangement

(1)	\oplus	Vcc
(2)	L	L
(3)	OUT	OUT PUT
(4)	Φ	GND (0 V)

EE-1006 Connector with Cable



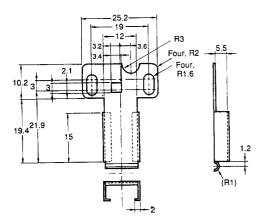


Terminal Arrangement

(1)	Red	Φ	VCC
(2)	Yellow	L	L
(3)	White	OUT	OUT PUT
(4)	Black	θ	GND (0 V)

EE-1006A Connector Holder





Precautions

Refer to pages 16 to 19 for general precautions.

The sensing window is made of a polycarbonate resin which withstands chloride solvents and strong acids, but which is, however, soluble in strong alkali, aromatic hydrocarbons, and aliphatic hydrocaronate chloride solvents.

The casing material uses a PBT resin which withstands chemicals and oil, but which is, however, soluble in strong acid or alkali solvents.

The temperature of the terminals at the time of soldering must not exceed the following:

Item	Temprature	Permissible time	Remarks
Dip	260°C	10 sec	The portion between the base of the terminals and the position 1.5 mm
Iron	350°C	3 sec	from the terminal base must not be soldered.

The terminal base uses a polycarbonate resin, which could be deformed by excessive soldering heat.

To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.